NSN 5961-00-827-5415

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Inclosure Material:

Metal

Overall Length:

Between 0.250 inches and 0.450 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

35.0 breakdown voltage, collector-to-base, emitter open and 35.0 breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

5.00 amperes source cutoff current and 2.00 milliamperes source cutoff current

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

1 case and 2 pin

Specification Data:

80131-release2119 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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